TOSHIBA Bi-CMOS Integrated Circuit Silicon Monolithic

# TB62801FG

#### Linear CCD Clock Driver

The TB62801FG is a clock distribution driver for CCD linear image sensors.

The IC can functionally drive the CCD input capacitance. It also supports inverted outputs, eliminating the need for crosspoint control.

The IC contains a 1 to 4 clock distribution driver for the main clock and 4-bit buffers for control signals.

### Features

- High drivability: Guaranteed driving 450 [pF] load capacitance @fclock = 20 [MHz]
- Operating temperature range: Ta = -25°C to 60°C

### Pin Connection (top view)





Weight: 0.5 g (typ.)

# Logic Diagram



# **Pin Description**

Pin No.	Pin Name	Functions	Remarks		
1	2B_out	Light-load drive output (inverted)	Driver output for CCD last-stage clock		
2	2B_in	Light-load drive input	Driver input for CCD last-stage clock		
3	CP_in	Light-load drive input	CCD clamp gate driver input		
4	V <sub>CC</sub>	Power supply			
	GND	Ground			
5	V <sub>CC</sub>	Power supply			
6	CK_in	Heavy-load drive input	Driver input for CCD transfer clock		
7	SH_in	Light-load drive input	CCD shift gate driver input		
8	RS_in	Light-load drive input	CCD reset gate driver input		
9	RS_out	Light-load drive output (not inverted)	CCD reset gate driver output		
10	SH_out	Light-load drive output (not inverted)	CCD shift gate driver output		
11	φ	Heavy-load drive output (not inverted)	Driver output for CCD transfer clock		
12	$\overline{\phi}$	Heavy-load drive output (inverted)	Driver output for CCD transfer clock		
	GND	Ground			
13	$\overline{\phi}$	Heavy-load drive output (inverted)	Driver output for CCD transfer clock		
14	φ	Heavy-load drive output (not inverted)	Driver output for CCD transfer clock		
15	CP_out	Light-load drive output (not inverted)	CCD clamp gate driver output		
16	2B_out	Light-load drive output (not inverted)	Driver output for CCD last-stage clock		

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# **Truth Table**

In	put	Output				
	L	2B out	Н			
2B in	Н	2 <u>D_</u> 001	L			
20_111	L	2P. out	L			
	Н	CP_out	н			
CP in	L	CP out	L			
	Н	CF_000	Н			
	L	¢	L			
CK in	Н	Ψ	н			
CK_III	L	-	н			
	Н	Ψ	L			
SH in	L	SH out	L			
3⊓_11	Н	SII_OUT	н			
	L	PS out	L			
N0_III	Н	NS_001	Н			

# Maximum Ratings (Ta = 25°C)

Charac	teristic	Symbol	Rating	Unit
Power supply voltage	je	V <sub>CC</sub>	-0.5 to 7.0	V
Input voltage		V <sub>IN</sub>	–1.2 to V <sub>CC</sub> +0.5	V
Output voltage		V <sub>O</sub> –0.5 to V <sub>CC</sub>		V
Input clamp diode c	urrent (V <sub>i</sub> < 0)	I <sub>IK</sub>	-50	mA
Output clamp diode	current (V <sub>O</sub> < 0)	IOK	-50	mA
Output current	High level	I <sub>OH</sub> (O/ 0 )	-16.0	mA
excluding other than $\phi$ , $\overline{\phi}$ outputs	Low level	I <sub>OL</sub> (O/ 0 )	16.0	mA
1	High level	IOH (ቀ/ 🖣 )	-100	mA
φ output current	Low level	IOL (ቀ/ 🖣 )	150	mA
Operating temperate	ure	Topr	Topr -25 to 60	
Storage temperature	е	T <sub>stg</sub> –40 to 100		
Junction temperatur	re	Tj	150	
Power dissipation		PD	1.5	W

Note: Output current is specified as follows:  $V_{OH}$  = 4.0 V,  $V_{OL}$  = 0.5 V.

# **Recommended Operating Conditions**

Characteris	Symbol	Min	Тур.	Мах	Unit	
Power supply voltage	V <sub>CC</sub>	4.7	5.0	5.5	V	
Input voltage	V <sub>IN</sub> 0			V <sub>CC</sub>	V	
Output voltage	V <sub>O</sub> 0		_	V <sub>CC</sub>	V	
Output current	High level	I <sub>OH</sub> (O/ $\overline{O}$ )		_	-8.0	mA
excluding φ, φ outputs	Low level	I <sub>OL</sub> (O/ 0 )			8.0	mA
output current	High level	I <sub>OH</sub> (ቀ/ 🛉 )		_	-20.0	mA
(Note)	Low level	I <sub>OL</sub> (ቀ/ 🖣 )		_	20.0	mA
Operating temperature	T <sub>opr</sub>	-25	25	60	°C	
Input rise/fall time	t <sub>ri</sub> /t <sub>fi</sub>		2.5	5.0	ns	

Note: Output current is specified as follows:  $V_{CC} = 4.7 \text{ V}$ ,  $V_{OH} = 4.5 \text{ V}$ ,  $V_{OL} = 0.2 \text{ V}$ . Input rise/fall time is specified as 10 % to 90 % of waveform amplitude.

# **Electrical Characteristics**

# DC Characteristics (unless otherwise specified, $V_{CC} = 4.7$ to 5.5 V, Ta = -25 to 60°C)

Characteristic		Symbol	Test Circuit	Test Condition	V <sub>CC</sub>	Min	Тур.	Max	Unit			
	High	VIH	1 2	_	—	V <sub>CC</sub>	V					
input voltage	Low	V <sub>IL</sub>	1, 2	—	4.7	0	_	0.8	v			
Input clamp voltag	ge	VIK	3	I <sub>IK</sub> = -30 mA	4.7	_	_	1.0	V			
				I <sub>OH</sub> = -10 mA	4.7	4.5	_	V <sub>CC</sub>	-			
		V <sub>OH</sub> (ቀ/ $\overline{\phi}$ )	4, 5	I <sub>OH</sub> = -50 mA	4.7	4.0	_	V <sub>CC</sub>				
				I <sub>OH</sub> = -300 mA	4.7	2.5	_	V <sub>CC</sub>	V			
output voltage				I <sub>OL</sub> = 100 μA	4.7	0	_	0.2	V			
		$V_{OL}$ ( $\phi/\overline{\phi}$ )	6, 7	I <sub>OL</sub> = 50 mA 4.7 0 —								
				I <sub>OL</sub> = 300 mA	4.7	0	_	2.5	1			
		$V_{av}(0,\overline{0})$	4 5	$I_{OH} (O / \overline{O}) = -4 \text{ mA}$ 4.7 4.5		_	V <sub>CC</sub>					
Output voltage ex	cluding	VOH (O/ O )	4, 5	$I_{OH} (O / \overline{O}) = -16 \text{ mA}$	4.7	4.0	_	V <sub>CC</sub>	V			
φ, φ outputs	-	V <sub>OL</sub> (O/ 0 )	6, 7	$I_{OL} (O / \overline{O}) = 4 \text{ mA}$	4.7	0	_	0.2				
				$I_{OL}$ (O / $\overline{O}$ ) = 16 mA	4.7	0	_	0.5				
Input voltage		I <sub>IN</sub>	8	$V_{IN} = V_{CC}$ or GND	5.5	_	_	1.0	μA			
Static current consumption	Total	ICC	9	$\phi$ outputs: High or Low $\overline{\phi}$ outputs: Low or High Other outputs are High	5.5	_	_	15.0	mA			
	Each bit	$\Delta I_{CC}$	10	One input: $V_{IN} = 0.5 V$ Other inputs: $V_{CC}$ or GND				1.5				
Output off mode supply voltage		V <sub>POR</sub>	—	See description on next page.		_	3.0	_	V			

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# **Output Low-Level Fixed Mode at Power-On**

- To avoid malfunction at power on, this IC incorporates the following functions:
- All outputs are fixed to low level until  $V_{\rm CC}$  reaches more than 3 V.
- When  $V_{CC}$  reaches 3 V (typ.), internal logic depends on input signals.
- $V_{CC}$  must be more than 4.7 V for normal operation.



# AC Characteristics (input transition rise or fall time: $t_r/t_f = 2.5$ ns)

Characteristic	Symbol	Test Condition	Normal Temperature/ V <sub>CC</sub> = 5.0 V			All Temperatures/ V <sub>CC</sub> = 4.7 to 5.5 V		Unit	Reference Measurement Diagram	
			Min	Тур.	Max	Min	Max			
	$t_{\rm eff}(\phi, \overline{\phi})$	$C_L = 450 \text{ pF}$	7.0	10.0	14.0	7.0	16.0	ns	Measurement diagram 1	
	·ϼϹϴͺͺϘͺϘͺʹ	$C_L = 350 \text{ pF}$	6.0	9.0	13.0	6.0	15.0			
	$t \cdots (\phi/\phi)$	$C_L = 450 \text{ pF}$	7.0	10.0	14.0	7.0	16.0			
Propagation delay time	<sup>τ</sup> ρΗL (Ψ Ψ )	$C_L = 350 \text{ pF}$	6.0	9.0	13.0	6.0	15.0			
r topagation delay time		$C_L = 30 \text{ pF}$	3.0	5.0	7.0	2.5	8.0	- ns	Measurement diagram 2	
	ιрLΗ (О/О)	$C_L = 15 \text{ pF}$	2.0	4.0	6.0	1.5	7.0			
	t <sub>pHL</sub> (O/ O )	$C_L = 30 \text{ pF}$	3.0	5.0	7.0	2.5	8.0			
		$C_L = 15 \text{ pF}$	2.0	4.0	6.0	1.5	7.0			
Output skew excluding $\phi, \ \overline{\phi}$ outputs to (skw)		$C_L = 30 \text{ pF}$	0	_	2.0	_	2.0	ns	Measurement diagram 3	
Output crosspoints (\phi1/\phi2)	V <sub>T</sub> (crs)	C <sub>L</sub> = 300 to 450 pF	—		—	1.5		V	Measurement diagram 4	

#### **Waveform Measuring Point**



#### **Measurement Diagram 4**

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# Reference Data (typ. value)















# **Test Circuit**

### **DC Parameters**

Pins marked with an asterisk (\*) are test pins. Ground the input pins that are not being used as test pins so that their logic is determined. Unless otherwise specified, bits of the same type are measured in the same way.

#### • V<sub>IH</sub>/V<sub>IL</sub>

(1) Light-load drive bit



(2) Heavy-load drive bit



• V<sub>IK</sub>





• V<sub>OH</sub> (O/\$)



• V<sub>OH</sub> (ō/̄ф)

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• V<sub>OL</sub> (O/\$)



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V<sub>OL</sub> (ō/̄φ)



• I<sub>IN</sub>





• Icc



Note 1: The input logic of the heavy-load drive clock input pin (pin 6) is the same for High or Low.

• Δ**I**cc



Note 2: When measuring input pins, connect the input pins that are not being measured to GND or power.

#### **AC Parameters**

Pins marked with an asterisk (\*) are test pins. Ground the input pins that are not being used as test pins so that their logic is determined. Unless otherwise specified, bits of the same type are measured in the same way.

#### • Propagation Delay Time

(1) Light-load drive bit



(2) Heavy-load drive bit



• Light-Load Drive Output Skew



Heavy-Load Drive Output Crosspoints



# **Example of an Application Circuit**

#### (1) Connection to the TCD1503C





### **Precautions on Use**

This IC does not include built-in protection circuits for excess current or overvoltage. If the IC is subjected to excess current or overvoltage, it may be destroyed. Therefore systems incorporating the IC should be designed with the utmost care.

Particular care is necessary in the design of the output,  $V_{\rm CC}$  and GND lines since the IC may be destroyed by short circuits between outputs, air contamination faults, or faults due to improper grounding.

(2) Connection to the TCD1703C



Note: Driving the CCD requires a lot of power. Toshiba recommends the use of a bypass capacitor connected to the 5 V power supply to stabilize voltage.

Two TB62801FGS devices are used in this application: one is used to drive all the control bits and the four transfer clock bits, the other to drive the remaining four transfer clock bits.

# Package Dimensions

HSOP16-P-300-1.00

Unit: mm



Weight: 0.5 g (typ.)

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